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2.4-2.5GHz,2 stages, 30W, S band 28V GaN MMIC PA module

Description

The Y2MAH2425-30 is a 30-watt ,2 stage integrated Power Amplifier Module with high gain, high efficiency, designed for CW or linear back off applications, with frequencies from 2.4 to 2.5GHz. The module is $50~\Omega$ input, and partially output matched and requires minimal external components, total effective size less than 3*1.5cm.



The module implements innovative MMIC concept, housed in cost effective 10*6mm plastic open cavity package.

VDS= 28V , Vgs-drive =-2.55V, IDQ-Driver =3 mA, Vgs-Final =-2.67V, IDQ-Final =35 mA,
CW.

Freq (MHz)	P1dB (dBm)	P1dB (W)	P1dB Gain(dB)	P3dB (dBm)	P3dB (W)	P3dB Eff(%)
2400	45. 73	37. 40	33. 16	45. 98	39. 61	77. 25
2450	44. 79	30. 12	34. 30	45. 55	35. 87	77. 75
2500	44. 18	26. 21	33. 66	45.04	31.89	77. 23

Product Features

• Operating Frequency Range: 2.4-2.5GHz

• Operating Drain Voltage: +28 V (Up to 32V)

• 50 Ω Input, Output partially matched

• Psat: ≥30W @28V (CW)

• Power gain:>30dB

• Efficiency:>75%

• 6x10 mm Surface Mount Package and total design less than 3*1.5cm

• Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

Applications

• 2450MHz ISM applications

Pin Configuration and Description



Pin No.	Symbol	Description
1	Vds-driver	
4	Vgs-driver	
6	RF in	
21,22	RF out/Vds-final	



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29	Vgs-final	
32	Open	Must leave as open, No GND
3, 8-11,14-17,19,24,26-28,33-35	NC	No internal connection
2,5,7,12, 13,18,20,23,25, 30, 31,36 Package Base	GND	DC/RF Ground. Must be soldered to EVB ground plane over array of vias for thermal and RF performance. Solder voids under Pkg Base will result in excessive junction temperatures causing permanent damage.

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DrainSource Voltage	V _{DSS}	150	Vdc
GateSource Voltage	V _{GS}	-10 to +2	Vdc
Operating Voltage	V _{DD}	+36	Vdc
Input CW Power	RFin	16	dBm
Storage Temperature Range	Tstg	-65 to +150	°C
Case Operating Temperature	Tc	+150	°C
Operating Junction Temperature	TJ	+225	°C

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case, FEA	Do 10	TBD	°C/W
T _C = 25°C, 50W Pulsed CW at 3GHz	Rejc	IBD	-0/00

Table 3. Electrical Characteristics

Parameter	Condition	Min	Тур	Max	Unit
Frequency Range		2400		2500	MHz
Power Gain		31	32		dB
Роит	Pin=13dBm		45		dBm
Drain Efficiency @ P _{SAT} 75 %					
Unless otherwise noted: TA = 25°C, V _{DD} =28 V, Pulse Width=20 us, Duty cycle=10%					

Load Mismatch of per Section (On Test Fixture, 50 ohm system): $V_{DD} = 28 \text{ V}$,

VSWR 10:1 at pulse CW Output Power @Pin=13Bm 2.45GHz	No Device Degradation
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TYPICAL CHARACTERISTICS

Figure 1. Network analyzer output S11/S21 (Pin=0dBm)

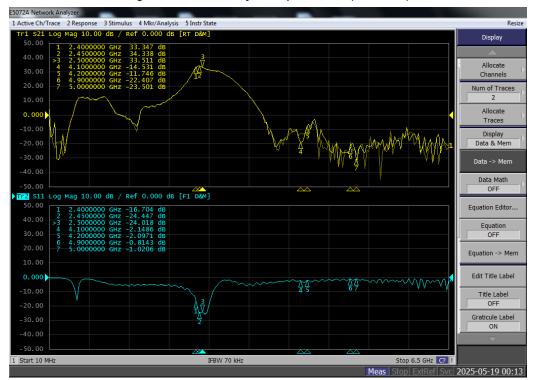
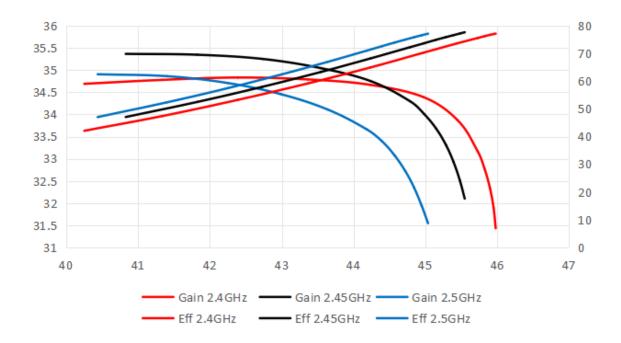
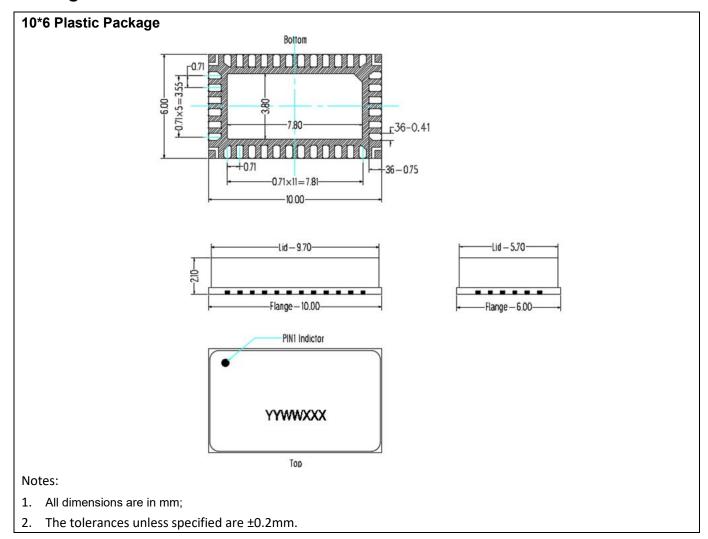


Figure 3. Power Gain and, efficiency Vs Pout

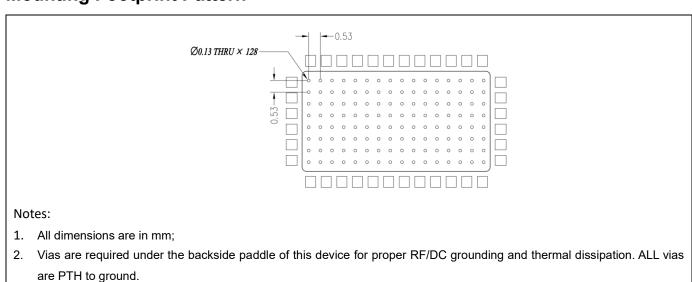


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Package Dimensions



Mounting Footprint Pattern





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Revision history

Table 6. Document revision history

Date	Revision	Datasheet Status
2025/5-19	Rev 1.0	Advanced Datasheet Creation

Application data based on LWH-25-17

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